









	<h2 style="color: #E67E22;">IPD90N03S4L-02</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">IPD90N03S4L-02</a>
	<b>Hersteller / Marke:</b>	<a href="#">International Rectifier (Infineon Technologies)</a>
	<b>Teil der Beschreibung:</b>	IPD90N03S4L-02 Infineon Technologies
<b>Datenblätter:</b>	 <a href="#">IPD90N03S4L-02.pdf</a>	
<b>RoHs Status:</b>	Bleifrei / RoHS-konform	
<b>Lagerzustand:</b>	New original, 27650 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

### Spezifikationen

Teilenummer	<a href="#">IPD90N03S4L-02</a>
Hersteller	<a href="#">International Rectifier (Infineon Technologies)</a>
Beschreibung	IPD90N03S4L-02 Infineon Technologies
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	27650 pcs Stock
Serie	OptiMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	PG-TO252-3
Verlustleistung (max)	136W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	90A (Tc)
Rds On (Max) @ Id, Vgs	2.2 mOhm @ 90A, 10V
VGS (th) (Max) @ Id	2.2V @ 90µA
Gate Charge (Qg) (Max) @ Vgs	140nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	9750pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±16V
Verpackung	Tape & Reel (TR)

IPD90N03S4L-02 ist neu im Original, Suche IPD90N03S4L-02 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IPD90N03S4L-02 International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IPD90N03S4L-02: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>IPD90N03S4L-03</b> International Rectifier (Infineon Technologies) IPD90N03S4L-03 Infineon Technologies</p>	 <p><b>IPD90N03S4L03ATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 30V 90A TO252-3</p>	 <p><b>IPD85P04P4L06ATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH TO252-3</p>	 <p><b>IPD90N04S3-04</b> infineon IPD90N04S3-04 infineon</p>
 <p><b>IPD85P04P4L-06</b> International Rectifier (Infineon Technologies) IPD85P04P4L-06 INFINEON</p>	 <p><b>IPD90N03S4L02ATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 30V 90A TO252-3</p>	 <p><b>IPD85P04P407ATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH TO252-3</p>	 <p><b>IPD80R750P7ATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 800V 7A TO252-3</p>

### heiße Teile

Mehr

 IPD65R380E6	 IPD65R420CFD	 IPD65R420CFDA	 IPD65R600C6	 IPD65R600E6
 IPD65R660CFD	 IPD65R950C6	 IPD65R950CFD	 IPD70N03S4L-04	 IPD70N03S4L04XT
 IPD70N04S3-07	 IPD70N10S3-12	 IPD70N10S3L-12	 IPD70P04P4-09	 IPD70P04P4L-08
 IPD75N04S4-06	 IPD78CN10NG	 IPD800N06NG	 IPD80N04S3-06	 IPD80N04S3-06B
 IPD80N06S3-09	 IPD80P03P4L-07	 IPD80R1K0CE	 IPD80R1K4CE	 IPD85P04P4L-06
 IPD90N03S4L-03	 IPD90N04S03-04	 IPD90N04S3-04	 IPD90N04S3-H4	 IPD90N04S4-02
 IPD90N04S4-03	 IPD90N04S4-04	 IPD90N04S4-05	 IPD90N04S4L-04	 IPD90N06S3-06
 IPD90N06S3L-07	 IPD90N06S4-04	 IPD90N06S4-05	 IPD90N06S4-07	 IPD90N06S4L-03
 IPD90N06S4L-05	 IPD90N08S4-05	 IPD90N10S4L-06	 IPD90P03P4-04	 IPD90P03P4L-04
 IPD90P04P4-05	 IPD90P04P4L-04	 IPD90R1K2C3	 IPDH06N03LA	 IPDH4N03LA-G

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